Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.540 inches

Overall Height:

0.312 inches

Overall Width:

1.030 inches

Mounting Facility Quantity:

2

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Unthreaded hole

Features Provided:

Burn in

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 repetitive peak off-state voltage and 200.0 repetitive peak reverse voltage

Current Rating Per Characteristic:

25.00 amperes forward current, total rms horsepower metric and 260.00 amperes peak forward surge current nanoamperes

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector peak

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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